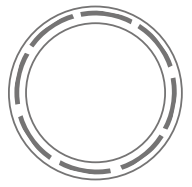


7AF-HMG Wafer Grinder

Designed for Advanced Grinding of Hard Materials



SYSTEM OVERVIEW

Revasum's 7AF-HMG grinding solution extends wheel life by nine times, increases uptime by 10%, boosts wafer output by 15 percent, and reduces the cost of ownership by seven times. With a return on investment of less than one year, the choice for SiC grinding is clear: choose the 7AF-HMG.

WHEEL LIFE IS NINE TIMES BETTER*

A SELF-DRESSING GRIND PROCESS*

THE RETURN ON INVESTMENT IS LESS THAN 12 MONTHS*

88 PERCENT FEWER WHEEL CHANGES*



*When back grinding SiC Wafers with 550 μ m target removal, and annual production of 25,000 wafers

FEATURES

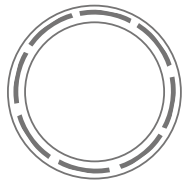
- Real-time grind performance monitoring
- A self-dressing grind process
- Grind spindles can be fitted with coarse or fine wheels
- Supports dual fine grind, dual coarse grind, and standard coarse/fine grind processing
- Wafer flipping available for double-side grinding applications
- In-situ, real-time thickness control
- Air bearing spindles equipped with 8Hp motors
- Robust, contemporary Windows 7 based operating system

BENEFITS

- Achieves <1 μ m TTV for most applications
- Astounding performance on wire sawn SiC wafers
- Designed to reduce consumables and operations costs
- Accommodates incoming wafers with varied thicknesses without presorting
- A wide process window, reduces setup time and increases process repeatability
- Surface finish can be optimized for subsequent processing
- Easy to maintain and to switch between wafer sizes
- Flexible process flows

7AF-HMG Wafer Grinder

Designed for Advanced Grinding of Hard Materials



GRINDING ACCURACY

TTV Within Wafer - $< 1\mu\text{m}$
Thickness Variation - $\pm 1\mu\text{m}$
Surface Roughness - 200 Å to 30 Å (wheel dependent)
Based on Si grinding

GRINDING

Grind Spindle Type - Air Bearing
Grind Spindle Speed - 500-4300 RPM
Grind Spindle Motor Output - 8Hp
Work Chuck Speed - 20-700 RPM
Work Chuck Type - Ceramic, porous vacuum
Spin / Rinse / Dry - Vacuum Chuck



TECHNICAL SPECS

Dimensions - (SAE) 73" W x 85" D x 76" H
(Metric) 1.86M x 2.15M x 2.46M
Footprint - $\sim 42.6 \text{ Ft}^2$ [$\sim 3.98 \text{ M}^2$]
Weight - $\sim 8500 \text{ lbs}$ [$\sim 3865 \text{ K}$]
Wafer Capacity - 50mm to 200mm
Wafer Measurement - In-situ, contact probe
Wafer Handling - Fully Automated
Load/Unload - 1 send, 1 receive
Configuration - 2 chucks, 2 spindles

APPLICATIONS

7AF-HMG is used for backside thinning and for bulk thinning of wire-sawn substrates for a hard materials, including:

- SiC
- InP
- Ge
- GaAs
- GaN
- and
- Sapphire
- LiNbO3
- more...